

# 2SC2655-HAF

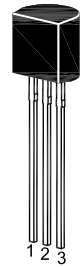
## NPN Silicon Epitaxial Planar Transistor

### Features

- The transistor is subdivided into two groups O and Y, according to its DC current gain
- On special request, these transistors can be manufactured in different pin configurations.
- Halogen and Antimony Free(HAF), RoHS compliant

### Applications

- For switching and AF amplifier applications



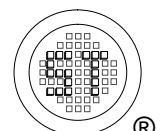
1. Emitter 2. Collector 3. Base  
TO-92 Plastic Package

### Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Collector Base Voltage	$V_{CBO}$	50	V
Collector Emitter Voltage	$V_{CEO}$	50	V
Emitter Base Voltage	$V_{EBO}$	5	V
Collector Current	$I_C$	2	A
Power Dissipation	$P_{tot}$	900	mW
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	- 55 to + 150	$^\circ\text{C}$

### Thermal Characteristics

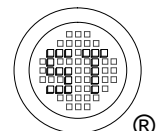
Parameter	Symbol	Max.	Unit
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	139	$^\circ\text{C/W}$



# 2SC2655-HAF

## Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit	
DC Current Gain at $V_{CE} = 2\text{ V}$ , $I_C = 0.5\text{ A}$  at $V_{CE} = 2\text{ V}$ , $I_C = 1.5\text{ A}$	Current Gain Group O Y	$h_{FE}$	70	-	140	-
		$h_{FE}$	120	-	240	-
		$h_{FE}$	40	-	-	-
Collector Base Cutoff Current at $V_{CB} = 50\text{ V}$	$I_{CBO}$	-	-	1	$\mu\text{A}$	
Emitter Base Cutoff Current at $V_{EB} = 5\text{ V}$	$I_{EBO}$	-	-	1	$\mu\text{A}$	
Collector Base Breakdown Voltage at $I_C = 1\text{ mA}$	$V_{(BR)CBO}$	50	-	-	V	
Collector Emitter Breakdown Voltage at $I_C = 10\text{ mA}$	$V_{(BR)CEO}$	50	-	-	V	
Emitter Base Breakdown Voltage at $I_E = 1\text{ mA}$	$V_{(BR)EBO}$	5	-	-	V	
Collector Emitter Saturation Voltage at $I_C = 1\text{ A}$ , $I_B = 50\text{ mA}$	$V_{CE(sat)}$	-	-	0.5	V	
Base Emitter Saturation Voltage at $I_C = 1\text{ A}$ , $I_B = 50\text{ mA}$	$V_{BE(sat)}$	-	-	1.2	V	
Gain Bandwidth Product at $V_{CE} = 2\text{ V}$ , $I_C = 0.5\text{ A}$	$f_T$	-	100	-	MHz	
Output Capacitance at $V_{CB} = 10\text{ V}$ , $f = 1\text{ MHz}$	$C_{ob}$	-	15	-	pF	



## Electrical Characteristics Curves

Fig. 1 Output Characteristics Curve

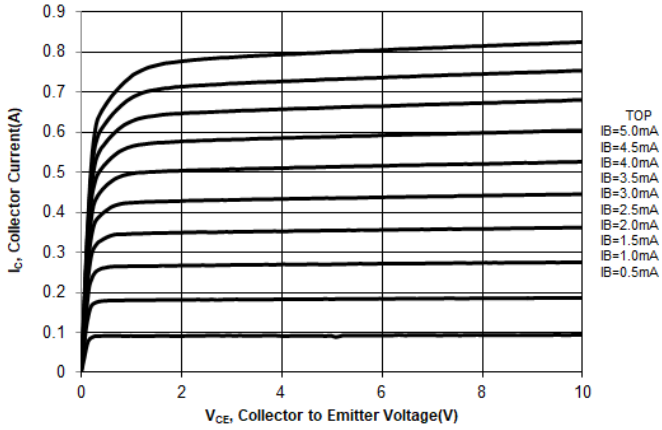


Fig. 2 Collector Current vs. Base to Emitter Voltage

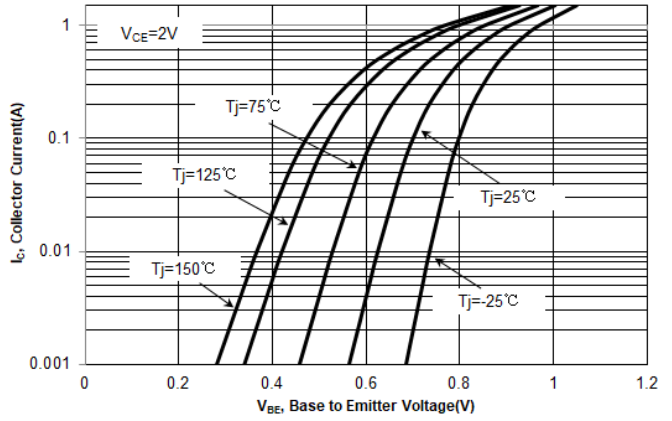


Fig. 3 DC Current Gain vs. Collector Current

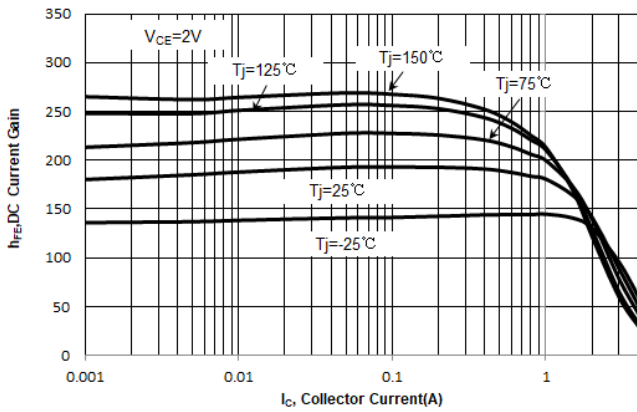
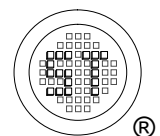
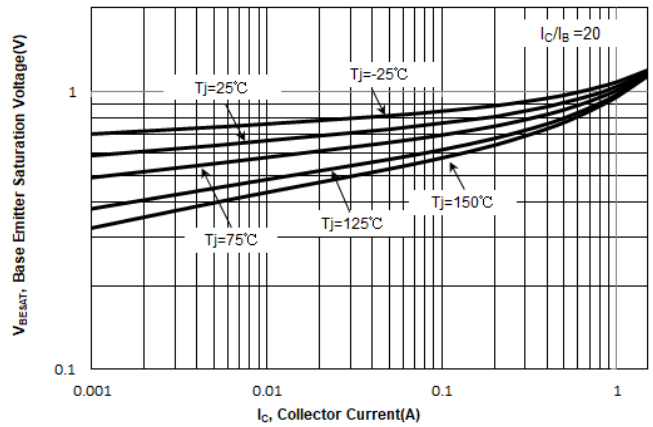


Fig. 4  $V_{BESAT}$  vs. Collector Current



## Electrical Characteristics Curves

Fig. 5  $V_{CESAT}$  vs. Collector Current

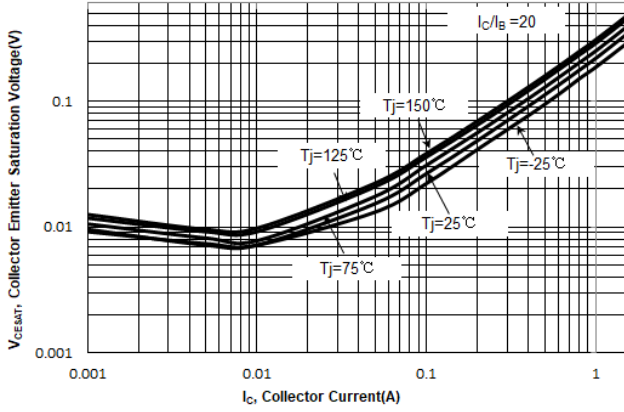


Fig. 6 Output Capacitance

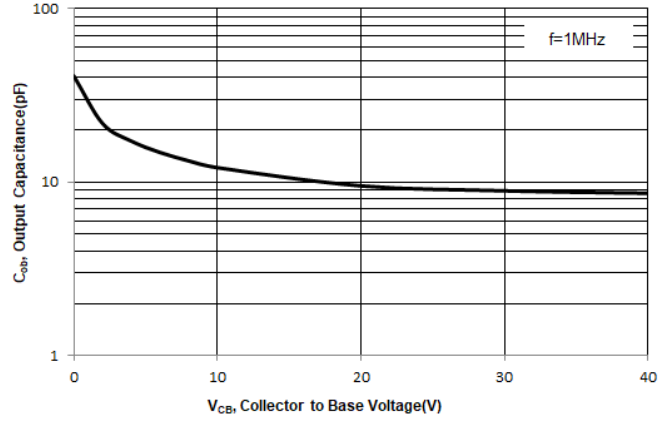
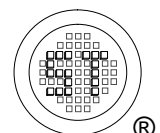
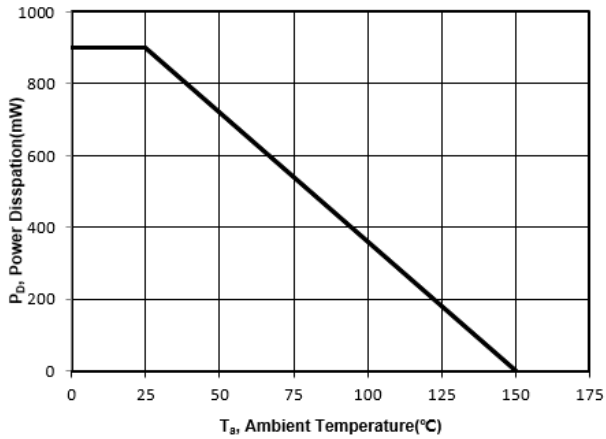
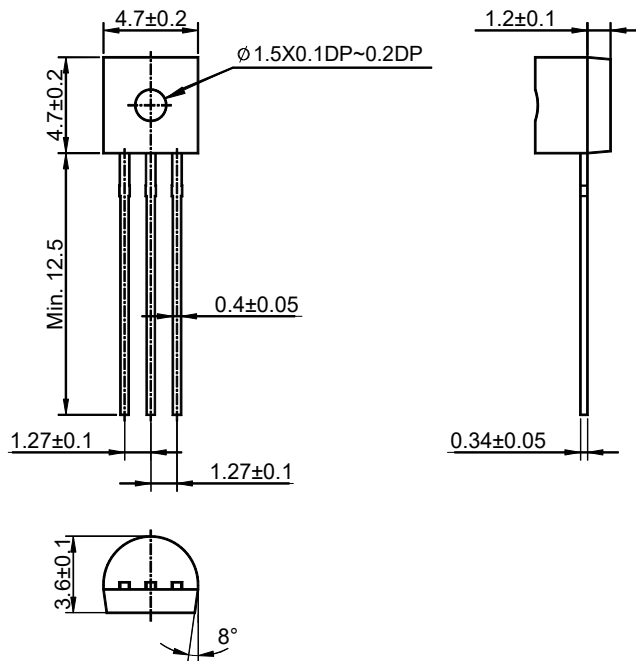


Fig 7. Power Derating Curve

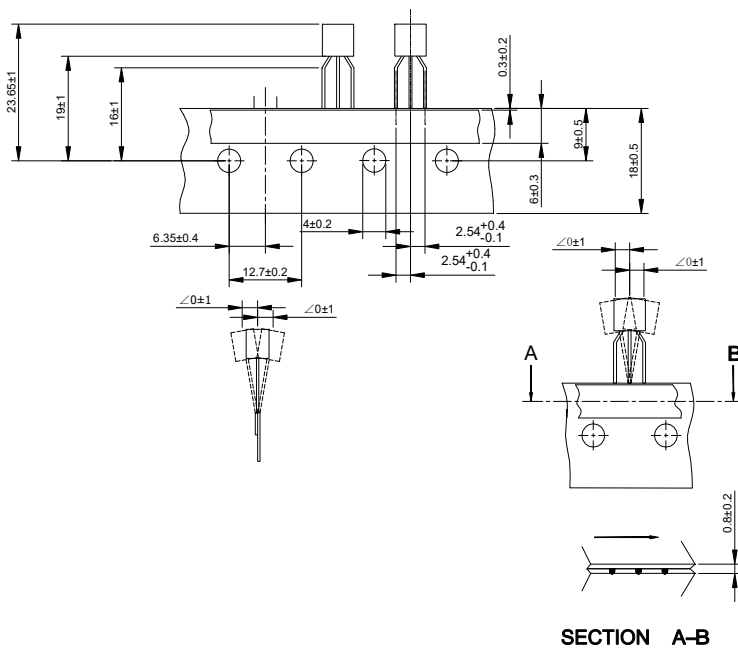


# 2SC2655-HAF

## TO-92 Package Outline (Dimensions in millimeters)



## TO-92 Ammo-Pack Outline (Dimensions in millimeters)



## Packing information

Package	Bulk Packing			Ammo-Packing	
	Per Bag Qty	Per Box Qty	Per Carton Qty	Per Box Qty	Per Carton Qty
TO-92	1,000	5,000	50,000	4,000	20,000

